

Data Sheet January 2000 File Number 3548.3

## 15A, 400V - 600V Ultrafast Dual Diodes

The RURG1540CC and RURG1560CC are ultrafast dual diodes with soft recovery characteristics ( $t_{rr} < 55$ ns). They have low forward voltage drop and are of silicon nitride passivated ion-implanted epitaxial planar construction.

These devices are intended for use as freewheeling/clamping diodes and rectifiers in a variety of switching power supplies and other power switching applications. Their low stored charge and ultrafast recovery with soft recovery characteristics minimize ringing and electrical noise in many power switching circuits reducing power loss in the switching transistors.

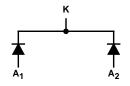
Formerly developmental type TA09905.

## **Ordering Information**

PART NUMBER	PACKAGE	BRAND		
RURG1540CC	TO-247	RURG1540C		
RURG1560CC	TO-247	RURG1560C		

NOTE: When ordering, use the entire part number.

## Symbol



#### **Features**

Ultrafast with Soft Recover	ery <55ns
Operating Temperature	175 <sup>0</sup> C
• Reverse Voltage Up to	600V

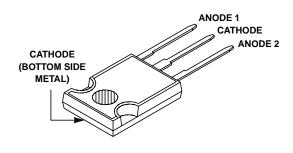
- · Avalanche Energy Rated
- Planar Construction

### **Applications**

- · Switching Power Supplies
- Power Switching Circuits
- · General Purpose

### **Packaging**

**JEDEC STYLE TO-247** 



Absolute Maximum Ratings (Per Leg) T <sub>C</sub> = 25°C			
	RURG1540CC	RURG1560CC	UNITS
Peak Repetitive Reverse VoltageV <sub>RRM</sub>	400	600	V
Working Peak Reverse Voltage	400	600	V
DC Blocking Voltage V <sub>R</sub>	400	600	V
Average Rectified Forward Current	15	15	Α
$(T_C = 145^{\circ}C)$			
Repetitive Peak Surge CurrentI <sub>FRM</sub>	30	30	Α
(Square Wave, 20kHz)			
Nonrepetitive Peak Surge Current	200	200	Α
(Halfwave, 1 Phase, 60Hz)			
Maximum Power Dissipation	100	100	W
Avalanche Energy (See Figures 7 and 8)	20	20	mJ
Operating and Storage Temperature	-65 to 175	-65 to 175	°С

## RURG1540CC, RURG1560CC

**Electrical Specifications** (Per Leg)  $T_C = 25^{\circ}C$ , Unless Otherwise Specified

	TEST CONDITION	RURG1540CC		RURG1560CC				
SYMBOL		MIN	TYP	MAX	MIN	TYP	MAX	UNITS
V <sub>F</sub>	I <sub>F</sub> = 15A	-	-	1.5	-	-	1.5	V
	I <sub>F</sub> = 15A, T <sub>C</sub> = 150 <sup>o</sup> C	-	-	1.3	-	-	1.3	V
I <sub>R</sub>	V <sub>R</sub> = 400V	-	-	100	-	-	-	μΑ
	V <sub>R</sub> = 600V	-	-	-	-	-	100	μΑ
	V <sub>R</sub> = 400V, T <sub>C</sub> = 150°C	-	-	500	-	-	-	μΑ
	$V_R = 600V, T_C = 150^{\circ}C$	-	-	-	-	-	500	μΑ
t <sub>rr</sub>	$I_F = 1A$ , $dI_F/dt = 100A/\mu s$	-	-	55	-	-	55	ns
	$I_F = 15A$ , $dI_F/dt = 100A/\mu s$	-	-	60	-	-	60	ns
t <sub>a</sub>	$I_F = 15A$ , $dI_F/dt = 100A/\mu s$	-	30	-	-	30	-	ns
t <sub>b</sub>	$I_F = 15A$ , $dI_F/dt = 100A/\mu s$	-	17	-	-	17	-	ns
$R_{ heta JC}$		-	-	1.5	-	-	1.5	°C/W

#### **DEFINITIONS**

 $V_F$  = Instantaneous forward voltage (pw = 300 $\mu$ s, D = 2%).

 $I_R$  = Instantaneous reverse current.

 $t_{rr}$  = Reverse recovery time (See Figure 6), summation of  $t_a$  +  $t_b$ .

t<sub>a</sub> = Time to reach peak reverse current (See Figure 6).

 $t_b$  = Time from peak  $I_{RM}$  to projected zero crossing of  $I_{RM}$  based on a straight line from peak  $I_{RM}$  through 25% of  $I_{RM}$  (See Figure 6).

 $R_{\theta JC}$  = Thermal resistance junction to case.

pw = Pulse width.

D = Duty cycle.

# **Typical Performance Curves**

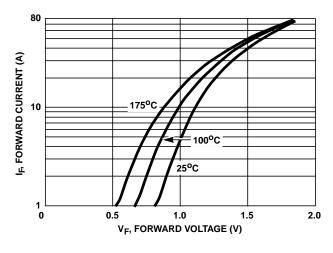


FIGURE 1. FORWARD CURRENT vs FORWARD VOLTAGE

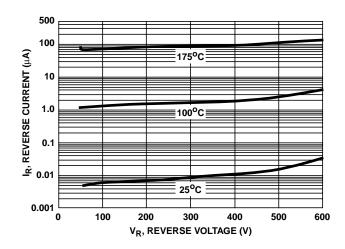


FIGURE 2. REVERSE CURRENT vs REVERSE VOLTAGE

### Typical Performance Curves (Continued)

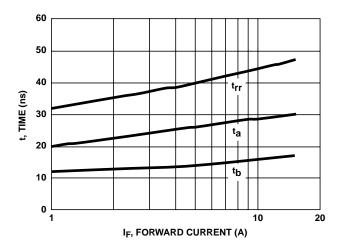


FIGURE 3. t<sub>rr</sub>, t<sub>a</sub> AND t<sub>b</sub> CURVES vs FORWARD CURRENT

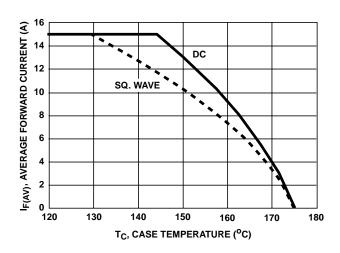


FIGURE 4. CURRENT DERATING CURVE

#### Test Circuits and Waveforms

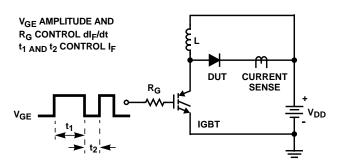


FIGURE 5. t<sub>rr</sub> TEST CIRCUIT

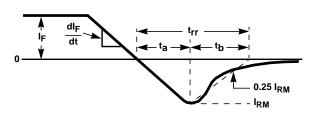


FIGURE 6. t<sub>rr</sub> WAVEFORMS AND DEFINITIONS

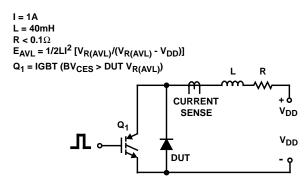


FIGURE 7. AVALANCHE ENERGY TEST CIRCUIT

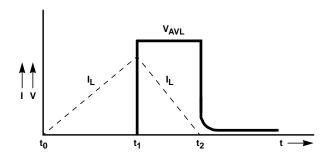


FIGURE 8. AVALANCHE CURRENT AND VOLTAGE WAVEFORMS

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